Attorney Docket No. 5649-926

Serial No. 10/054,540

Filed: January 22, 2002

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The listing of claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

1. (Previously Presented) An integrated circuit ferroelectric memory device, comprising:

an integrated circuit transistor having a source region and a drain region;

a ferroelectric capacitor on the integrated circuit transistor having first and second sidewalls, the ferroelectric capacitor including a first electrode consisting of a single material adjacent the transistor, a second electrode remote from the transistor and a ferroelectric film therebetween;

a contact plug directly connected to the first electrode that electrically couples the ferroelectric capacitor to the source region of the integrated circuit transistor;

an insulating layer on the first and second sidewalls of the ferroelectric capacitor, the insulating layer having a surface that is substantially coplanar with an upper surface of the second electrode;

- a plate line directly on the ferroelectric capacitor; and
- a stripe line adjacent the second electrode and remote from the first electrode.
- 2. (Original) A device according to Claim 1, wherein the plate line is directly on the second electrode of the ferroelectric capacitor.
- 3. (Original) A device according to Claim 1, wherein the integrated circuit ferroelectric memory device is free of a plug between the plate line and the second electrode.
- 4. (Original) A device according to Claim 3, wherein the integrated circuit ferroelectric memory device is free of an insulating layer between the plate line and the second electrode.

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5. (Original) A device according to Claim 4, wherein the second electrode has a width and wherein the plate line is directly on the second electrode across the width.

Claim 6 (Canceled).

7. (Previously Presented) A device according to Claim 1, wherein the stripe line comprises aluminum.

Claims 8-9 (Canceled).

- 10. (Original) A device according to Claim 1, wherein the first electrode comprises at least one of platinum and/or iridium dioxide.
- 11. (Original) A device according to Claim 1, wherein the ferroelectric film comprises at least one of PZT, SBT and/or BLT.
- 12. (Original) A device according to Claim 1, wherein the second electrode comprises at least one of iridium, ruthenium, platinum and/or iridium dioxide.

Claims 13-18 (Canceled).